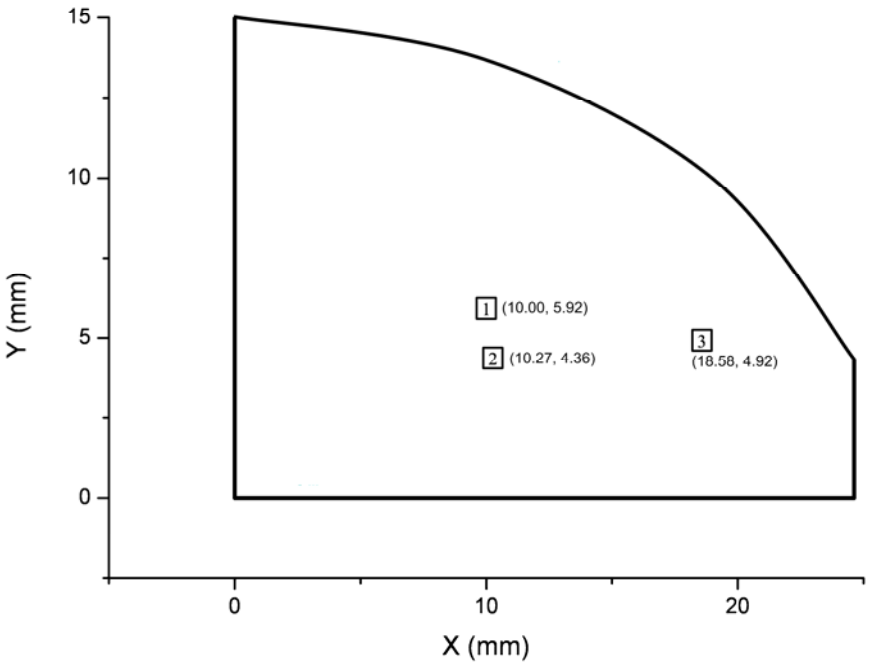
LRW-0064 Datasheet

Parent Wafer

Si Orientation	<100>
Si Thickness	500-560µm
Resistivity	0.001-0.005Ωcm
Oxide	300nm Dry Thermal Oxide

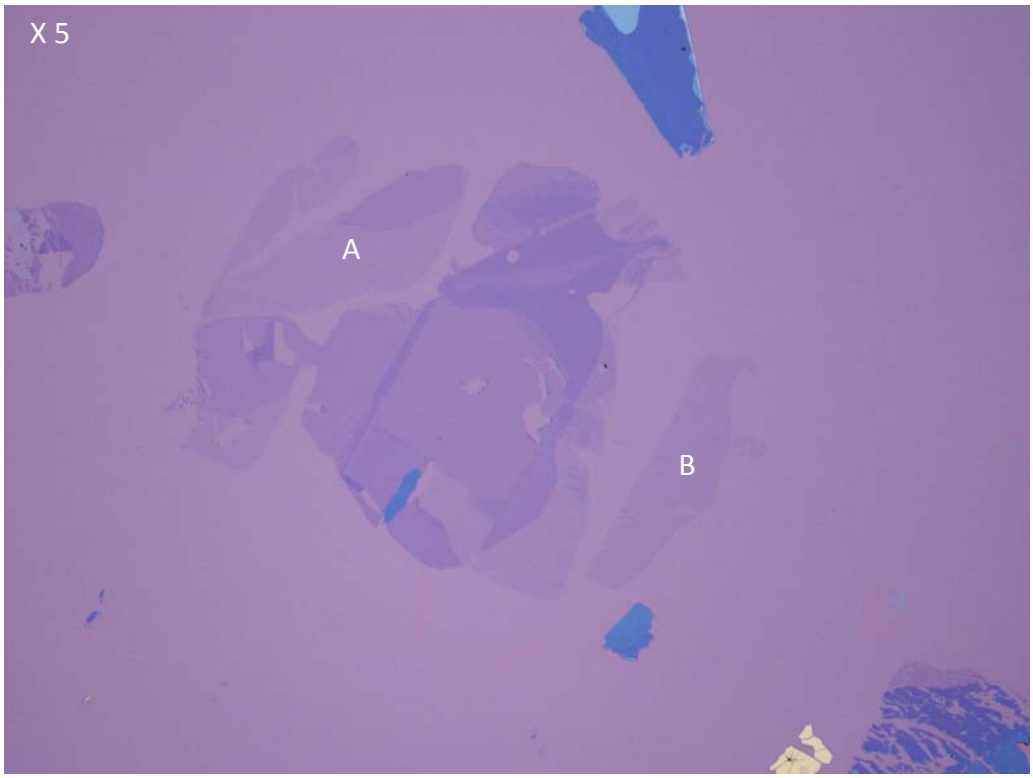
Substrate Map



Flake 1: x=10.00mm, y=5.92mm Area: >95000µm^2 (single layer)

Flake 2: x=10.27mm, y=4.36mm

Area: A>**86000µm^2** (**single layer**) B>**80000µm^2** (**single layer**)




B
X 20
200 µm

Flake 3: x=18.58mm, y=4.92mm Area: >**31000µm^2** (**single layer**)